

# Silicon Carbide Schottky Diode

#### **Features**

- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- Positive Temperature Coefficient on V<sub>F</sub>
- Temperature-independent Switching
- 175°C Operating Junction Temperature

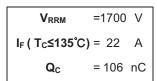
### **Benefits**

- Replace Bipolar with Unipolar Device
- Reduction of Heat Sink Size
- Parallel Devices Without Thermal Runaway
- Essentially No Switching Losses

## **Applications**

- Switch Mode Power Supplies
- Power Factor Correction
- Motor drive, PV Inverter, Wind Power Station

Part Number	Package	Marking
SC3S17010T7	TO-247-2	SC17010







## **Maximum Ratings**

Symbol	Parameter	Value	Unit	Test Conditions	Note
V <sub>RRM</sub>	Repetitive Peak Reverse Voltage	1700	V	T <sub>C</sub> = 25°C	
V <sub>RSM</sub>	Surge Peak Reverse Voltage	1700	V	T <sub>C</sub> = 25°C	
V <sub>R</sub>	DC Blocking Voltage	1700	V	T <sub>C</sub> = 25°C	
I <sub>F</sub>	Forward Current	22 10	А	T <sub>C</sub> ≤ 135°C T <sub>C</sub> ≤ 162°C	
I <sub>FSM</sub>	Non-Repetitive Forward Surge Current	110	Α	$T_C = 25^{\circ}C$ , $t_p = 8.3$ ms, Half Sine Wave	
P <sub>tot</sub>	Power Dissipation	300	W	T <sub>C</sub> = 25°C	Fig.3
T <sub>J</sub> , T <sub>STG</sub>	Operating Junction and Storage Temperature	-55 to 175	°C		
	TO-247 Mounting Torque	1	Nm	M3 Screw	

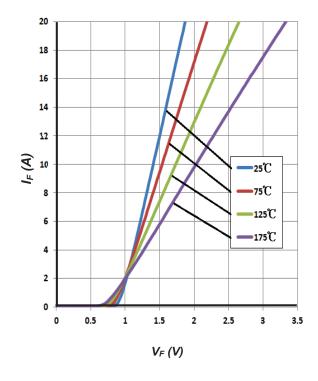
### **Electrical Characteristics**

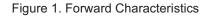
Symbol	Parameter	Тур.	Max.	Unit	Test Conditions	Note
V	Conversed Valley of	1.5	1.8	\/	I <sub>F</sub> = 10A, T <sub>J</sub> = 25°C	Fig. 4
V <sub>F</sub>	Forward Voltage	2.1	2.5	V	I <sub>F</sub> = 10A, T <sub>J</sub> = 175°C	Fig.1
	Decrees Occurrent	5	50		V <sub>R</sub> = 1700V, T <sub>J</sub> = 25°C	F: 0
I <sub>R</sub>	Reverse Current	25	200	μA	V <sub>R</sub> = 1700V, T <sub>J</sub> = 175°C	Fig.2
		990			V <sub>R</sub> = 0V, T <sub>J</sub> = 25°C, f = 1MHz	
С	Total Capacitance	45	/	pF	V <sub>R</sub> = 800V, T <sub>J</sub> = 25°C, f = 1MHz	Fig.5
		42	42		V <sub>R</sub> = 1700V, T <sub>J</sub> = 25°C, f = 1MHz	
	T 1 1 0 11 01	400	,		V <sub>R</sub> = 1700V, I <sub>F</sub> = 10A	F: 4
Qc	Total Capacitive Charge	106	/	nC	di/dt = 200A/μs, T <sub>J</sub> = 25°C	Fig.4

### **Thermal Characteristics**

Symbol	Parameter	Тур.	Unit	Note
R <sub>θJC</sub>	Thermal Resistance from Junction to Case	0.5	°C/W	Fig.6
$R_{\theta JA}$	Thermal Resistance from Junction to Ambient		°C/W	
T <sub>sold</sub>	T <sub>sold</sub> Soldering Temperature		°C	

# **RATING AND CHARACTERISTICS CURVES (SC3S17010T7)**





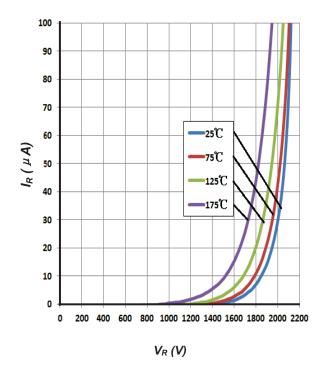
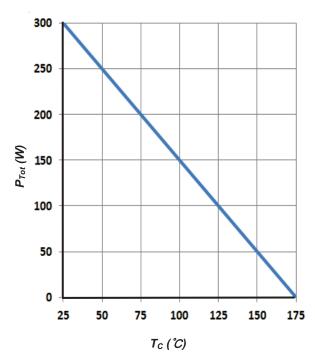


Figure 2. Reverse Characteristics



# **RATING AND CHARACTERISTICS CURVES (SC3S17010T7)**



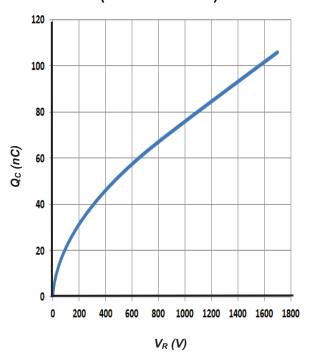
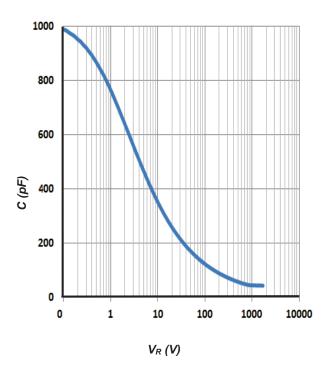


Figure 3. Power Derating







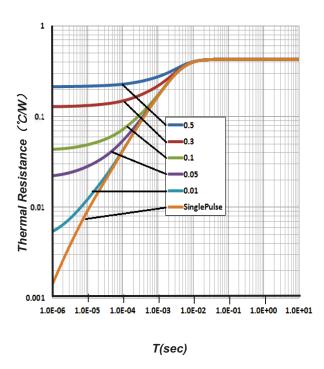
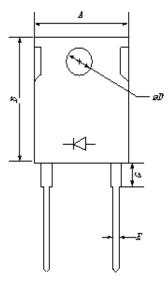


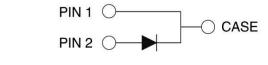
Figure 6. Transient Thermal Impedance



## **Package Dimensions**

### Package TO-247-2

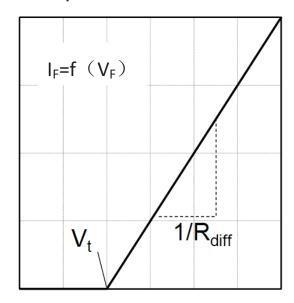




Symbol	Min. (mm)	Typ. (mm)	Max. (mm)
Α	14.18	15.75	17.33
В	18.45	20.5	22.55
С	4.50	5.00	5.50
D	3.15	3.50	3.85
E	1.08	1.20	1.32
F	18.27	20.30	22.33

# **Simplified Diode Model**

### **Equivalent IV Curve for Model**



### **Mathematical Equation**

$$V_F = V_t + I_F \times R_{diff}$$

$$V_t = -0.0013 \times T_j + 0.9779 \text{ [V]}$$

$$R_{diff} = 1.9 \times 10^{-6} \times T_j^2 + 1.7 \times 10^{-4} \times T_j + 0.0412 \text{ [}\Omega\text{]}$$

Note:

Tj = Diode Junction Temperature In Degrees Celsius, valid from 25°C to 175°C

I<sub>F</sub>= Forward Current Less than 20A

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